



PHYSICS

BOOKS - IE IRODOV PHYSICS (HINGLISH)

DIRECT CURRENT



1. How will the rending of the ammeter change

if the key K is closed?

2. A voltage V_0 is applied to a potentiometer whose sliding constant is exacly in the middle. A voltmeter V is connected between the sliding constant and one fixed end of the potentionmeter. If is assumed that the resistance of the voltmeter is not very high in comparison to the resistance of the potentiometer wire. What voltage will the voltmeter show : higher than, less than, or





3. To measure a small emf (of, say, a galvanic cell or a thermocouple) the so-called balancing method is employed. The circuit diagram of this method is shown in the figure. Here ~x is

the sought emf, is the source of current whose emf is much higher than ~x, G is a galvanornetcr with the zero in the middle of the scale, A is an ammeter, and R is the resistance box. How should one operate this circuit so as to ensure an accuracy in measuring ~x that is determined by the precision of the measuring devices?

4. Two resistors with resistances R_1 and R_2 are connected in series, and so are two capacitors with capacit ances C_1 and C_2 . The two systems arc connected in parallel and an external voltage is applied to the new system (see the figure accompanying the problem). What must be the relationship between R_1, R_2, C_1 , and C_2 for the potential difference between the points a and b to be zero?

5. All the resistances and ernfs shown in the figure accompanying the problem are assumed known. How many values of current can exist for such a circuit ? How many equations for finding these values must we construct on the basis of Kirchh off's first law and how many must we construct OII the basis of Kirchh off's second law'?



6. Twelve conductors are connected in such a way that they form a cube, and an emf source is connertr d into an edge of the cube. All the resistances and the emf's are known. There are eight junctions (eight vertices of the cube) and six loops (six faces of the cube) in the circuit. Construct tho equations for determining all the currents in the circuit.

7. A source of electric current with an emf \in_{α} and an Internal resistance r is connected to an external circuit with a resistance R. What must be the relationship between rand R for the power output in the external circuit to be maximal? What is the efficiency of the current source in this case, provided Lhat the power output in the external circuit is assumed to be the useful out put?



8. How must a large number of galvanie cells, each having the same emf G and tho same internal resistance r, be connected so that in an external circuit whose resistance is R the power out put is maximal ?

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9. A charged capacitor is discharged through a resistor two times. The time dependence of the logarithm of the discharge current obtained in the two experiments is

represented by the two straight lines 1 and 2, in the figure accompanying the problem. The experimental conditions differed only in one of the three parameters: the initial voltage of the capacitor U, the capacitance C, or the resistance R. Determine the parameter that was varied in these experiments and in which case this parameter is greater

10. The energy distribution function for electrons in a metal at absolute zero can be written as follows: $f(W) = CW^{rac{1}{2}}$, where C is a constant coefficient that is a combination of universal constants. This function terminates at W_F , which is the limiting energy, or the Fermi level. Using (4.36.1), establish how the limiting energy depends on electron concentration.



11. The dependence of the logarithm of conductivity, In a, on T^{-1} , where T is the temperature, for two semiconductors is shown in the figure. In which of the two semiconductors is the gap (the forbidden band) between the valence band and the conduction band wider ?

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12. The dependence of the logarithm of conductivity, In o, on $\frac{1}{T}$ for two

semiconductors is shown schematically in the

figure. In which respect do these semiconductors differ?

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13. The distribution of potential near the boundary between two semiconductors with different types of conduction depends on the direction of the applied external voltage. Which distribution corresponds to the blocking direction and which, to conduction? To what semiconductors do the left and right

branches of the curves in the figure belong?



14. The phenomenon of secondary electron emission consists in the following. When electrons bombard a solid surface, the surface emits secondary electrons (and partially reflects the primary electrons, which Impinge on the surface). Secondary electron emission is characterized by the secondary emission

coefficient δ , Which is the ratio of the secondary electron current to the primary current. The dependence of the secondary emission coeflicient on the primary electron energy W_1 for a certain dielectric is depicted in the figure. At $\delta=1$ the surface of the dielectric does not change its potential under electron bornbardment, since the number of electrons leaving tho surface every second is equal in this case to the number of electrons bombarding the surface every second. The two points a and b on the $\delta vs. W_1$ curve

correspond to $\delta = 1$. At which point is the

process stable and at which is it unstable?



15. Under secondary electron emission (see Problem 4.41), the energy distribution function $F(W_2)$ for secondary electrons is represented sufficiently well by two curves (1 and 2) shown in the figure accompanying the problem. Which of the two curves represents the primary electrons and which, the "true"

secondary electrons?

